

## 7-UNIT 400mA DARLINGTON TRANSISTOR ARRAY

**DESCRIPTION**

M54566DP is seven-circuit collector current sink type darlington transistor arrays. The circuits are made of PNP and NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

**FEATURES**

- High breakdown voltage ( $BV_{CEO} \geq 50V$ )
- High-current driving ( $I_c(\text{max}) = 400\text{mA}$ )
- Active L-level input

**APPLICATIONS**

Interfaces between microcomputers and high-voltage, high-current drive systems, drives of relays and printers, and MOS-bipolar logic IC interfaces.

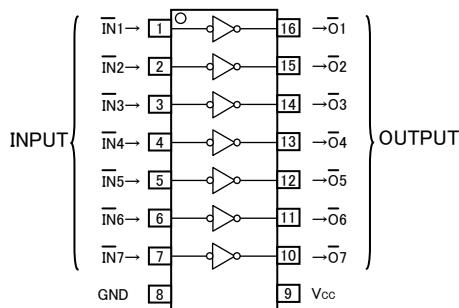
**FUNCTION**

The M54566 is produced by adding PNP transistors to M54522 inputs. Seven circuits having active L-level inputs are provided.

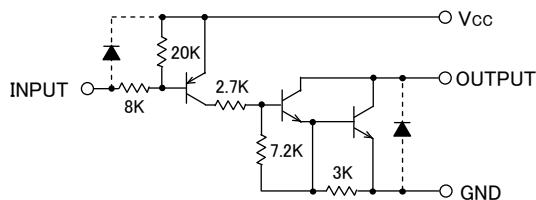
Resistance of  $8k\Omega$  is provided between each input and PNP transistor base. The input emitters are connected to Vcc pin (pin 9). Output transistor emitters are all connected to the GND pin (pin 8).

Collector current is 400mA maximum. Collector-emitter supply voltage is 50V maximum.

These ICs are optimal for drivers that are driven with N-MOSIC output and absorb collector current.

**PIN CONFIGURATION**

Package type 16P2X-B

**CIRCUIT DIAGRAM**

The seven circuits share the Vcc and GND.  
The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit:  $\Omega$

**ABSOLUTE MAXIMUM RATINGS** (Unless otherwise noted,  $T_a = -20 \sim +75^\circ\text{C}$ )

| Symbol           | Parameter                 | Conditions                                       | Ratings      | Unit |
|------------------|---------------------------|--|--------------|------|
| Vcc              | Supply voltage            |  | 10           | V    |
| V <sub>CEO</sub> | Collector-emitter voltage | Output, H  | - 0.5 ~ + 50 | V    |
| I <sub>c</sub>   | Collector current         | Current per circuit output, L                    | 400          | mA   |
| V <sub>i</sub>   | Input voltage             |  | - 0.5 ~ Vcc  | V    |
| P <sub>d</sub>   | Power dissipation         | $T_a = 25^\circ\text{C}$ , when mounted on board | 1.00         | W    |
| T <sub>opr</sub> | Operating temperature     |  | - 20 ~ + 75  | °C   |
| T <sub>stg</sub> | Storage temperature       |  | - 55 ~ + 125 | °C   |

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## RECOMMENDED OPERATING CONDITIONS

| Symbol          | Parameter   | Limits                         |     |                    | Unit |
|-----------------|---|--------------------------------|-----|--------------------|------|
|                 |   | min                            | typ | max                |      |
| V <sub>CC</sub> | Supply voltage  | 4                              | 5   | 8                  | V    |
| V <sub>O</sub>  | Output voltage  | 0                              | —   | 50                 | V    |
| I <sub>C</sub>  | Collector current (Current per 1 circuit when 7 circuits are coming on simultaneously)<br>V <sub>CC</sub> =5V | Duty Cycle<br>no more than 6%  | 0   | —                  | 350  |
|                 |   | Duty Cycle<br>no more than 20% | 0   | —                  | 200  |
| V <sub>IH</sub> | "H" input voltage   | V <sub>CC</sub> -0.2           | —   | V <sub>CC</sub>    | V    |
| V <sub>IL</sub> | "L" input voltage   | 0                              | —   | V <sub>CC</sub> -3 | V    |

## ELECTRICAL CHARACTERISTICS (Unless otherwise noted, Ta = -20~+75°C)

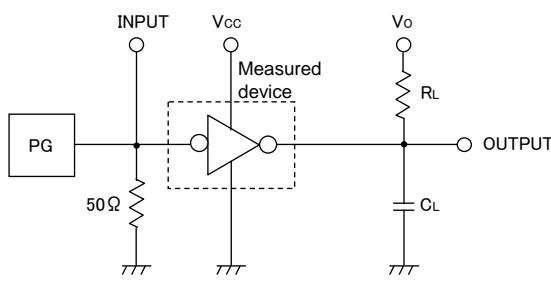
| Symbol               | Parameter                              | Test conditions   | Limits                 |       |       | Unit |
|----------------------|--|---|------------------------|-------|-------|------|
|                      |  |   | min                    | typ * | max   |      |
| V <sub>(BR)CEO</sub> | Collector-emitter breakdown voltage    | I <sub>CEO</sub> = 100 μA   | 50                     | —     | —     | V    |
| V <sub>CESAT</sub>   | Collector-emitter saturation voltage   | V <sub>I</sub> = V <sub>CC</sub> -3V  | I <sub>C</sub> = 350mA | —     | 1.1   | 2.2  |
|                      |  |   | I <sub>C</sub> = 200mA | —     | 0.9   | 1.6  |
| I <sub>I</sub>       | Input current                          | V <sub>I</sub> = V <sub>CC</sub> -3.5V  | —                      | -0.3  | -0.58 | mA   |
| I <sub>CC</sub>      | Supply current (one circuit coming on) | V <sub>CC</sub> = 5V, V <sub>I</sub> = V <sub>CC</sub> -3.5V                  | —                      | 1.4   | 3.0   | mA   |
| h <sub>FE</sub>      | DC amplification factor                | V <sub>CE</sub> = 4V, V <sub>CC</sub> = 5V, I <sub>C</sub> = 350mA, Ta = 25°C | 2000                   | 10000 | —     | —    |

\*:The typical values are those measured under ambient temperature (Ta) of 25°C. There is no guarantee that these values are obtained under any conditions.

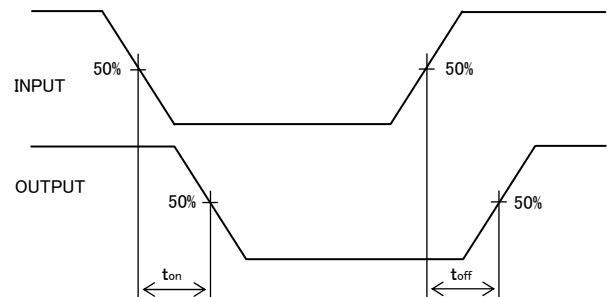
## SWITCHING CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

| Symbol           | Parameter     | Test conditions   | Limits |      |     | Unit |
|------------------|---------------|-------------------|--------|------|-----|------|
|                  |               |                   | min    | typ  | max |      |
| t <sub>on</sub>  | Turn-on time  | CL = 15pF(note 1) | —      | 95   | —   | ns   |
| t <sub>off</sub> | Turn-off time |                   | —      | 2500 | —   | ns   |

## NOTE 1 TEST CIRCUIT

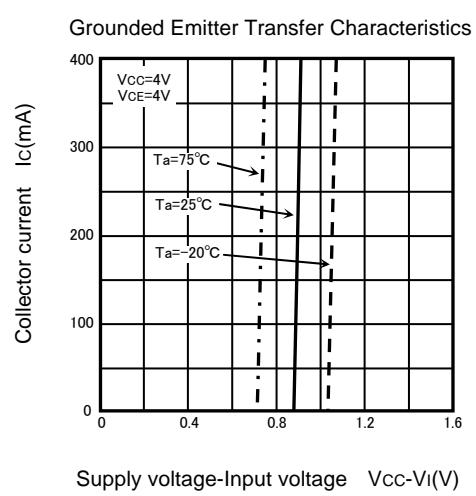
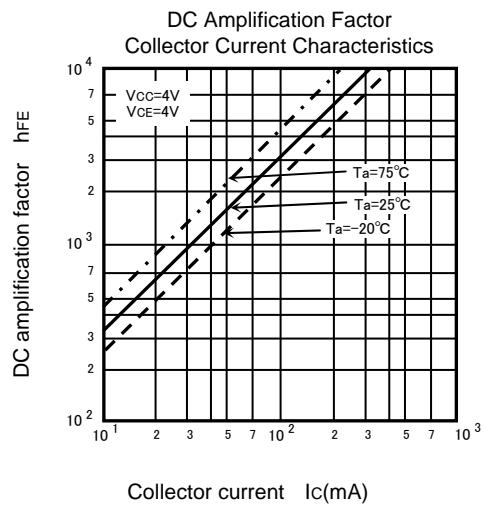
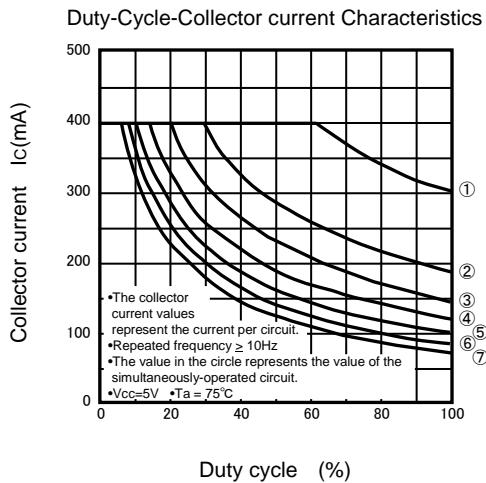
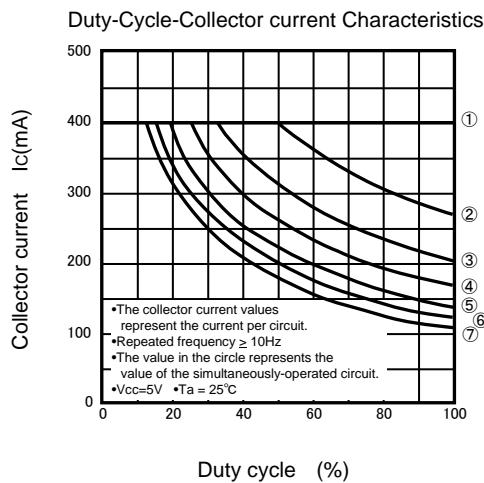
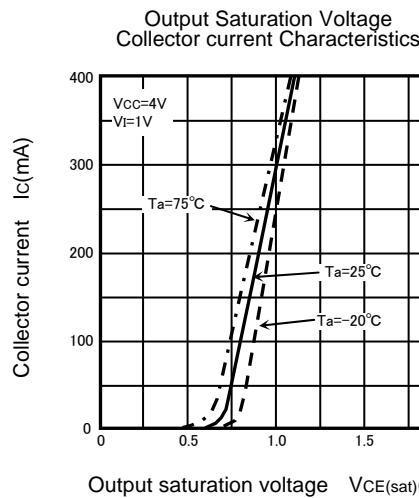
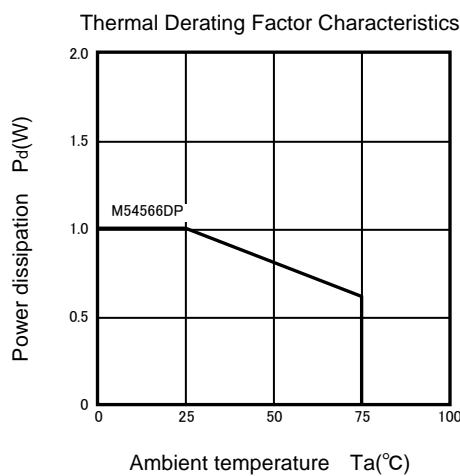


## TIMING DIAGRAM

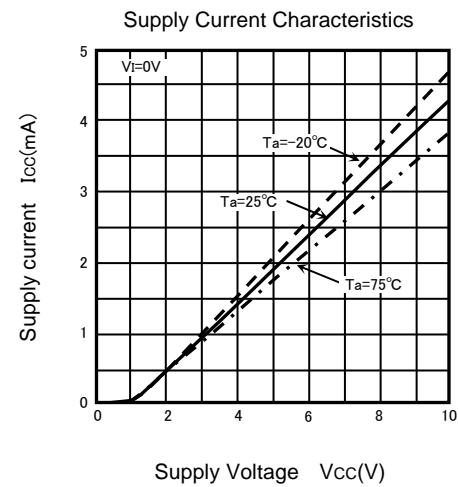
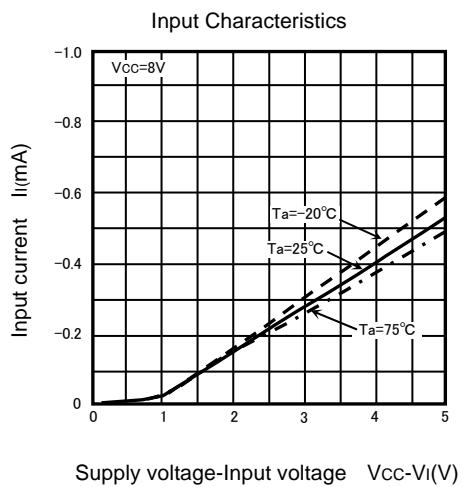


- (1) Pulse generator (PG) characteristics: PRR = 1kHz, tw = 10 μs, tr = 6ns, tf = 6ns, Zo = 50Ω , VI = 1 to 4V
- (2) Input-output conditions : RL = 30Ω , VO = 10V, VCC = 4V
- (3) Electrostatic capacity CL includes floating capacitance at connections and input capacitance at probes

## TYPICAL CHARACTERISTICS



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## PRELIMINARY

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## PACKAGE OUTLINE

## 16P2X-B

Plastic 16pin 225mil SOP

